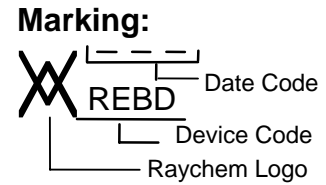
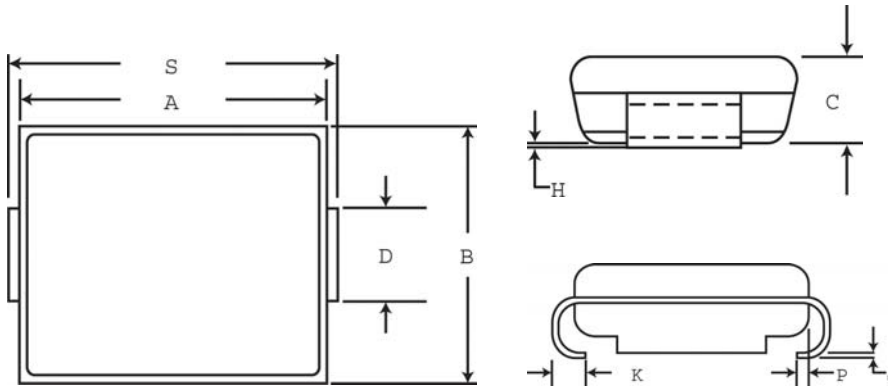


Specification Status: RELEASED

PHYSICAL DESCRIPTION



	A		B		C		D**		H		J		K	
	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX
mm:	4.06	4.57	3.30	3.94	1.90	2.44	1.95	2.20	0.05	0.20	0.15	0.31	0.76	1.52
in*:	(0.160)	(0.180)	(0.130)	(0.155)	(0.075)	(0.096)	(0.077)	(0.086)	(0.002)	(0.008)	(0.006)	(0.012)	(0.030)	(0.060)

	P	S	
	REF	MIN	MAX
mm:	0.51	5.21	5.59
in*:	(0.020)	(0.205)	(0.220)

*Rounded off approximation

** D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P

Other Physical Characteristics

Form Factor: SMB (Surface Mount, JEDEC DO-214AA Package)
 Lead Material: Tin/Lead Finish
 Encapsulation Material: Epoxy, meets UL94 V-0 requirements
 Solderability: per MIL-STD-750, Method 2026
 Solder Heat Withstand: per MIL-STD-750, Method 2031
 Solvent Resistance: per MIL-STD-750, Method 1022
 Mechanical Shock: per MIL-STD-750, Method 2016
 Vibration: per MIL-STD-750, Method 2056

Tape and Reel packaging per EIA 481-1

Agency Recognition: UL
 Precedence: This specification takes precedence over documents referenced herein.
 CAUTION: Operation beyond the rated voltage or current may result in rupture, electrical arcing or flame.

Materials Information

ELV Compliant



DEVICE RATINGS @ 25° C (Both Polarities)

Parameter	Symbol	Value	Units
Repetitive Off-State Voltage, Maximum at ID = 5 μ A	VDM	270	V
Non-Repetitive Peak Impulse Current	IPP ₁	100	A
Telcordia GR-1089 CORE 10x1000 μ s	IPP ₂	150	A
TIA-968 lightning Type A Metallic 10/560 μ s	IPP ₃	200	A
Double exponential Waveform	IPP ₄	500	A
Telcordia GR-1089 Intrabuilding 2/10 μ s	IPP ₅	400	A
(Notes 1 and 2) IEC61000-4-5 (Voc 1.2/50us) 8/20 μ s	IPP ₆	100	A
ITU-T K.20/K.21 (Voc 10/700us) 5/310 μ s	IPP ₇	100	A
TIA-968 lightning Type B (Voc 9/720us) 5/320 μ s			
Critical Rate of Rise of On-State Current			
Power Pulse Amplifier, C=30 μ F, V=600V	di/dt	500	A/ μ s
Maximum 2x10 μ sec waveform, V _{OC} =2.5kV, I _{SC} =500A peak	di/dt	330	A/ μ s

DEVICE THERMAL RATINGS

Parameter	Symbol	Value	Units
Storage Temperature Range	TSTG	-55 to 150	°C
Operating Temperature Range Blocking or conducting state	TA	-40 to 125	°C
Overload Junction Temperature Maximum; Conducting state only	TJ	+150	°C
Maximum Lead Temperature for Soldering Purpose; for 10 seconds	TL	+260	°C

ELECTRICAL CHARACTERISTICS Both polarities (T_J @ 25°C unless otherwise noted)

Characteristics	Symbol	Min	Typ	Max	Units
Breakover Voltage (+25°C) (dv/dt = 0.4kV/ μ s, I _{SC} =900mA, V _{DC} = 500V (both polarities))	VBO	----	310	365	V
Breakover Voltage Temperature Coefficient	dVBO/dTJ	----	0.1	-----	%/°C
Off-State Current (VD1=50V)	ID1	----	-----	2.0	μ A
(VD2=VDM)	ID2=IDM	----	-----	5.0	μ A
On-State Voltage (IT=1A)	VT	----	-----	4.0	V
(PW \leq 300 μ sec, Duty Cycle \leq 2% (Note 2))					
Breakover Current	IBO	----	-----	800	mA
Holding Current (Note 2)	IH	150	----	----	mA
Peak Onstage Surge Current (Measured @ 60Hz, 1 cycle, 600V)	ITSM	60	----	----	A
Critical Rate of Rise of Off-State Voltage (Linear waveform, V _D = 0.8 X Rated V _{BO} , T _J = +25°C)	dv/dt	2000	----	----	V/ μ s
Capacitance (f=1.0 Mhz, 50Vdc bias, 1Vrms)	C1	----	50	----	pF
(f=1.0 Mhz, 2Vdc bias, 1Vrms)	C2	----	110	----	pF

Note 1. Allow cooling before test second polarity

Note 2. Measured under pulse conditions to reduce heating

VOLTAGE-CURRENT CHARACTERISTIC

